

1000MHz 34dB Gain With GaAs Push-Pull Amplifier Module

1. Product profile

1.1 General description

High dynamic range power doubler amplifier module operating at a supply voltage of 24VDC in an SOT115 package, using a cascaded power doubler MMIC with GaAs Technology from USA , adding ESD and surge protective devices.

CAUTION



This device is sensitive to Electro Static Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Excellent linearity
- Low noise
- Low return loss
- Rugged construction
- High reliability

1.3 Applications

- CATV systems operating in the 40MHz to 1000MHz frequency range.

1.4 Quick reference data

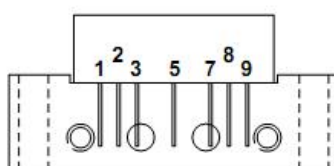
Bandwidth 40MHz to 1000MHz; $V_B = 24\text{ V}$; $T_{mb} = 30\text{ }^{\circ}\text{C}$; $Z_S = Z_L = 75\text{ }\Omega$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$f = 50\text{ MHz}$	34.0	35.0	35.5	dB
		$f = 1000\text{ MHz}$	35.0	-	-	dB
I_{tot}	total current	$V_B = 24\text{ V}$	260	290	320	mA

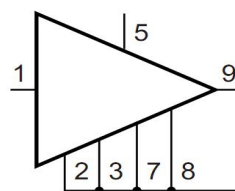
2. Pin information

Pin	Description
1	input
2	common
3	common
5	+ V_B
7	common
8	common
9	output

Simplified Outline



Graphic Symbol



3. Operating conditions

3.1 Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134) ($T_A = +25^{\circ}\text{C}$)

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V_B	-	25	V
Input Voltage ^[1]	V_i	-	65	dBmV
Operating Case Temperature	T_C	-20	+90	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-40	+100	$^{\circ}\text{C}$

[1] In case of single tone

3.2 Recommended operating conditions ($Z_S = Z_L = 75 \Omega$)

Parameter	Symbol	Test Conditions	MIN	TYP	MAX	Unit
Supply Voltage	V_B		23.5	24.0	24.5	V
Operating Case Temperature	T_C		-20	+30	+80	$^{\circ}\text{C}$

4. Electrical characteristics

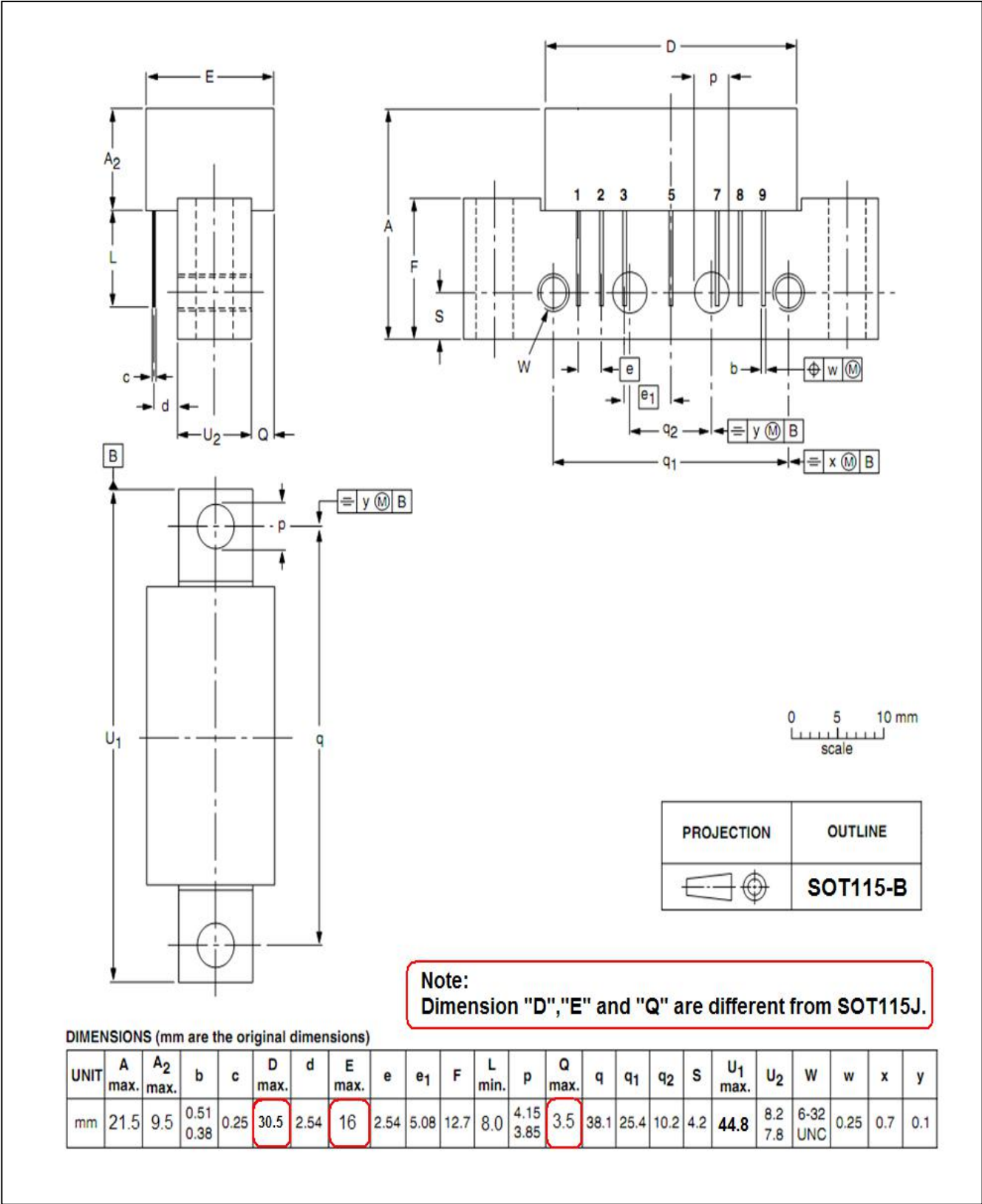
($T_C = 30 \pm 5^{\circ}\text{C}$, $V_B = 24 \text{ V}$, $Z_S = Z_L = 75 \Omega$)

Parameter	Symbol	Test Conditions	MIN	TYP	MAX	Unit
Power Gain	G_p	$f = 50\text{MHz}$	34.0	35.0	35.5	dB
Gain Slope	SL	$f = 50 \text{ to } 1000\text{MHz}$	1.0	1.5	2.5	dB
Gain Flatness	FL	$f = 50 \text{ to } 1000\text{MHz}$	-	-	± 0.5	dB
Noise Figure	NF	$f = 1000\text{MHz}$	-	5.5	6.0	dB
Operating Current	IB	$V_B = 24\text{VDC}$, RF OFF	260	290	320	mA
Composite Triple Beat	CTB	98 channels, $V_o = 48\text{dBmV}$ at 743.25 MHz, flat output level across the band	-	-57	-	dB
Cross Modulation	XM		-	-56	-	dB
Composite 2nd Order Beat	CSO		-	-59	-	dB
Input Return Loss	S11	$f = 40 \text{ to } 550\text{MHz}$	18	-	-	dB
		$f = 550 \text{ to } 1000\text{MHz}$	16	-	-	dB
Output Return Loss	S22	$f = 40 \text{ to } 550\text{MHz}$	16	-	-	dB
		$f = 550 \text{ to } 1000\text{MHz}$	16	-	-	dB

5. Package outline

Rectangular single-ended package; aluminum flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads.

SOT115-B



UNIT: mm